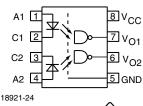
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High Speed Optocoupler, 10 MBd, Dual, SOIC-8 Package







LINKS TO ADDITIONAL RESOURCES







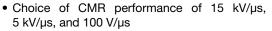
DESCRIPTION

The SFH675xT-series, is a dual channel 10 MBd optocoupler utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transister output, providing less leakage compared to an open collector Schottky clamped transister output. The internal shield provides a guaranteed common mode transient immunity of 5 kV/µs for the SFH6756T and 15 kV/µs for the SFH6757T. The use of a 0.1 µF bypass capacitor connected between pin 5 and 8 is recommended.

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1

FEATURES





• External creepage distance > 5 mm

• High speed: 10 Mbd typical

• + 5 V CMOS compatibility

 Guaranteed AC and DC performance over temperature: - 40 °C to + 100 °C temperature range

- Pure tin leads
- Meets IEC 60068-2-42 (SO₂) and IEC 60068-2-43 (H₂S) requirements
- · Low input current capability: 5 mA
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

APPLICATIONS

- Microprocessor system interface
- PLC, ATE input/output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- · AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- Ground loop elimination

ORDERING INFORMATION			
S F H	6 7 5	# T	SOIC-8
PART	NUMBER	TAPE AND REEL	6.1 mm
AGENCY CERTIFIED / PACKAGE	CMR (kV/μs)	CMR (kV/μs)	CMR (kV/μs)
UL, cUL	0.1	5	15
SOIC-8	SFH6755T	SFH6756T	SFH6757T

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TRUTH TABLE (positive logic)					
LED	ENABLE	OUTPUT			
On	Н	L			
Off	Н	Н			
On	L	Н			
Off	L	Н			
On	NC	L			
Off	NC	Н			

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Average forward current (single channel)		I _F	20	mA		
Average forward current (per channel for dual channel)		I _F	15	mA		
Reverse input voltage		V_R	5	V		
Surge current	t = 100 μs	I _{FSM}	200	mA		
Output power dissipation (single channel)		P _{diss}	35	mW		
Output power dissipation (per channel for dual channel)		P _{diss}	25	mW		
OUTPUT						
Supply voltage	1 min maximum	V _{CC}	7	V		
Output current		I _O	50	mA		
Output voltage		V _O	7	V		
Output power dissipation (single channel)		P _{diss}	85	mW		
Output power dissipation (for dual channel)		P _{diss}	60	mW		
COUPLER						
Isolation test voltage	t = 1 s	V _{ISO}	4000	V _{RMS}		
Storage temperature		T _{stg}	- 55 to + 150	°C		
Operating temperature		T _{amb}	- 40 to + 100	°C		
Lead solder temperature	for 10 s		260	°C		
Solder reflow temperature (1)	for 1 min	T _{sld}	260	°C		

Notes

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

RECOMMENDED OPERATING CONDITIONS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT		
Operating temperature		T _{amb}	- 40	100	°C		
Supply voltage		V _{CC}	4.5	5.5	V		
Input current low level		I _{FL}	0	250	μΑ		
Input current high level		I _{FH}	5	15	mA		
Output pull up resistor		R_L	330	4K	Ω		
Fanout	$R_L = 1 \text{ k}\Omega$	N		5	-		

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

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THERMAL CHARACTERISTICS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
LED power dissipation	at 25 °C	P _{diss}	100	mW	T _B
Output power dissipation	at 25 °C	P _{diss}	500	mW]
Maximum LED junction temperature		T _{jmax}	125	°C	₹ ^{θ_{DB}}
Maximum output die junction temperature		T _{jmax}	125	°C	$\int_{\Gamma_{\rm D}}$
Thermal resistance, junction emitter to emitter		$\theta_{\sf EE}$	412	°C/W	PEZ, Z
Thermal resistance, junction detector to emitter		θ_{DE}	133	°C/W	T_{c} θ_{ET} T_{E1} θ_{ET} θ_{ET}
Thermal resistance, junction emitter to board		θ_{EB}	120	°C/W	θ _{EE}
Thermal resistance, junction detector to board		θ_{DB}	77	°C/W	PEB ₹ PEB
Thermal resistance, junction emitter to case		θ_{FC}	110	°C/W	20510 T _B T _B

Note

The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal
Characteristics of Optocouplers application note.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, and V _{CC} = 5.5 V, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Input forward voltage	I _F = 10 mA	V _F	1.1	1.4	1.7	V		
Reverse current	V _R = 5 V	I _R	-	0.01	10	μA		
Input capacitance	f = 1 MHz, V _F = 0 V	C _I	-	55	-	pF		
OUTPUT								
High level supply current	$V_E = 0.5 \text{ V}, I_F = 0 \text{ mA}$	Іссн	-	4.1	7	mA		
(single channel)	$V_E = V_{CC}$, $I_F = 0$ mA	Іссн	-	3.3	6	mA		
High level supply current (dual channel)	I _F = 0 mA	I _{CCH}	-	6.5	12	mA		
Low level supply current	V _E = 0.5 V, I _F = 10 mA	I _{CCL}	-	4	7	mA		
(single channel)	$V_E = V_{CC}$, $I_F = 10 \text{ mA}$	I _{CCL}	-	3.3	6	mA		
Low level supply current (dual channel)	I _F = 10 mA	I _{CCL}	-	6.5	12	mA		
High level output current	$V_E = 2 \text{ V}, V_O = 5.5 \text{ V}, I_F = 250 \mu\text{A}$	I _{OH}	-	0.002	1	μΑ		
Low level output voltage	$V_E = 2 \text{ V}, I_F = 5 \text{ mA},$ $I_{OL} \text{ (sinking)} = 13 \text{ mA}$	V _{OL}	-	0.2	0.6	V		
Input threshold current	$V_E = 2 \text{ V}, V_O = 5.5 \text{ V},$ I_{OL} (sinking) = 13 mA	I _{TH}	-	2.4	5	mA		

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

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SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Propagation delay time to high output level	$R_L = 350 \ \Omega, \ C_L = 15 \ pF$	t _{PLH}	20	48	100	ns	
Propagation delay time to low output level	$R_L = 350 \ \Omega, \ C_L = 15 \ pF$	t _{PHL}	25	50	100	ns	
Pulse width disortion	$R_L = 350 \ \Omega, \ C_L = 15 \ pF$	t _{PHL} - t _{PLH}	-	2.9	35	ns	
Propagation delay skew	$R_L = 350 \Omega$, $C_L = 15 pF$	t _{PSK}	-	8	40	ns	
Output rise time (10 to 90 %)	$R_L = 350 \ \Omega, \ C_L = 15 \ pF$	t _r	-	23	-	ns	
Output fall time (90 to 10 %)	$R_L = 350 \Omega, C_L = 15 pF$	t _f	-	7	-	ns	

Note

• Over recommended temperature (T_A = - 40 °C to + 100 °C), V_{CC} = 5 V, I_F = 7.5 mA unless otherwise specified. All typicals at T_{amb} = 25 °C, V_{CC} = 5 V.

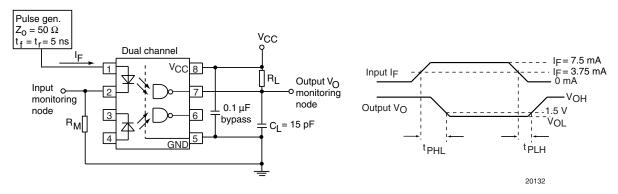


Fig. 1 - Dual Channel Test Circuit for t_{PLH} , t_{PHL} , t_{r} and t_{f}

COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
	$ \begin{aligned} V_{CM} &= 10 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, \\ V_{O(min.)} &= 2 \text{ V}, R_L = 350 \ \Omega, T_{amb} = 25 \ ^{\circ}C \ ^{(1)} \end{aligned} $	CM _H	100	-	i	V/µs		
Common mode transient immunity (high)	$ \begin{aligned} V_{CM} &= 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, \\ V_{O(min.)} &= 2 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ} C^{(2)} \end{aligned} $	CM _H	5000	10 000	i	V/µs		
	$ \begin{aligned} V_{CM} &= 1 \text{ kV, } V_{CC} = 5 \text{ V, } I_F = 0 \text{ mA,} \\ V_{O(min.)} &= 2 \text{ V, } R_L = 350 \Omega, T_{amb} = 25 ^{\circ}\text{C} ^{(3)} \end{aligned} $	CM _H	15 000	25 000	i	V/µs		
	$ \begin{vmatrix} V_{CM} = 10 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, \\ V_{O(\text{max.})} = 0.8 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}\text{C} ^{(1)} \\ \end{vmatrix} $	CM _L	100	-	i	V/µs		
Common mode transient immunity (low)	$ \begin{aligned} & V_{CM} = 50 \text{ V, } V_{CC} = 5 \text{ V, } I_F = 7.5 \text{ mA,} \\ &V_{O(\text{max.})} = 0.8 \text{ V, } R_L = 350 \Omega, \ T_{amb} = 25 \text{ °C} \end{aligned} $	CM _L	5000	10 000	i	V/µs		
	$ \begin{aligned} & V_{CM} = 1 \text{ kV, } V_{CC} = 5 \text{ V, } I_F = 7.5 \text{ mA,} \\ &V_{O(\text{max.})} = 0.8 \text{ V, } R_L = 350 \ \Omega, \ T_{\text{amb}} = 25 \ ^{\circ}\text{C} \end{aligned} $	CM _L	15 000	25 000	i	V/µs		

Notes

- (1) For SFH6755T
- (2) For SFH6756T
- (3) For SFH6757T



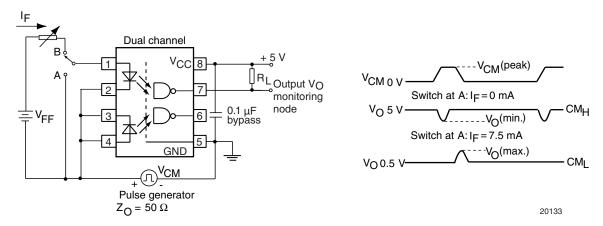


Fig. 2 - Dual Channel Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification	According to IEC 68 part 1			55 / 100 / 21				
Comparative tracking index		CTI	175		399			
Peak transient overvoltage		V _{IOTM}	6000			V		
Peak insulation voltage		V _{IORM}	560			V		
Safety rating - power output		P _{SO}			350	mW		
Safety rating - input current		I _{SI}			150	mA		
Safety rating - temperature		T _{SI}			165	°C		
Creepage distance			5			mm		
Clearance distance			4			mm		
Insulation thickness			0.2			mm		

Note

• As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of prodective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

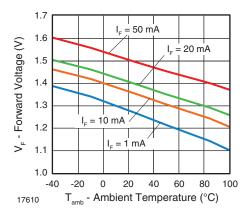


Fig. 3 - Forward Voltage vs. Ambient Temperature

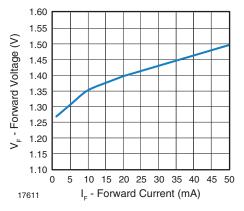


Fig. 4 - Forward Voltage vs. Forward Current

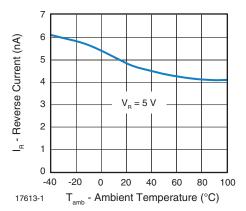


Fig. 5 - Reverse Current vs. Ambient Temperature

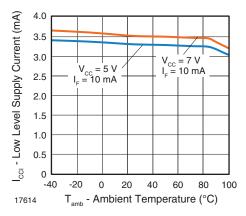


Fig. 6 - Low Level Supply Current vs. Ambient Temperature

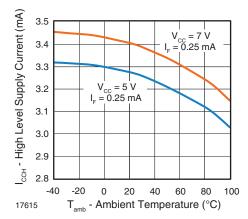


Fig. 7 - High Level Supply Current vs. Ambient Temperature

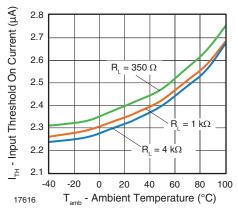


Fig. 8 - Input Threshold on Current vs. Ambient Temperature

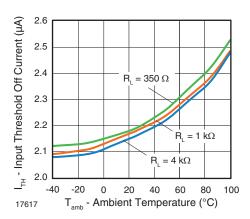


Fig. 9 - Input Threshold off Current vs. Ambient Temperature

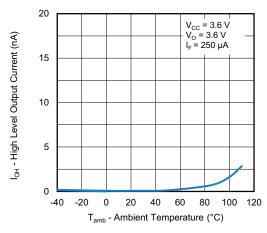


Fig. 12 - High Level Output Current vs. Ambient Temperature

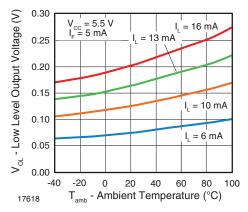


Fig. 10 - Low Level Output Voltage vs. Ambient Temperature

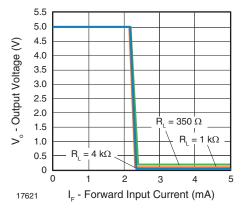


Fig. 13 - Output Voltage vs. Forward Input Current

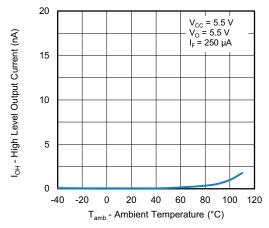


Fig. 11 - Low Level Output Current vs. Ambient Temperature

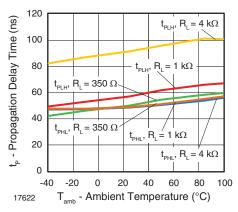


Fig. 14 - Propagation Delay vs. Ambient Temperature

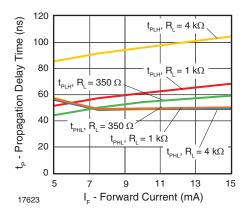


Fig. 15 - Propagation Delay vs. Forward Current

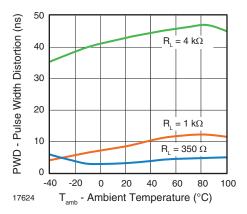


Fig. 16 - Pulse Width Distortion vs. Ambient Temperature

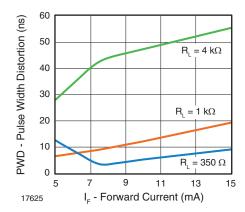


Fig. 17 - Pulse Width Distortion vs. Forward Current

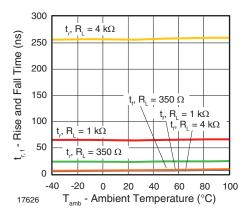


Fig. 18 - Rise and Fall Time vs. Ambient Temperature

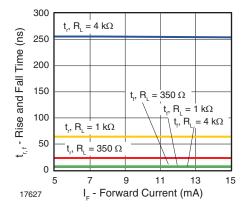
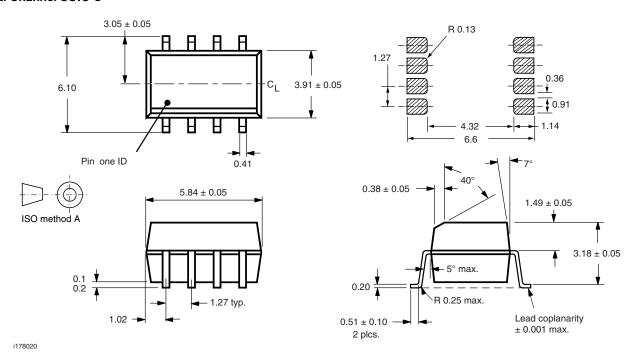


Fig. 19 - Rise and Fall Time vs. Forward Current

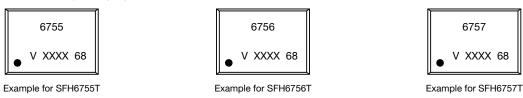


PACKAGE DIMENSIONS in millimeters

Dual Channel SOIC-8



PACKAGE MARKING (example)



Notes

- XXXX = LMC (lot marking code)
- "X1" is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

ESD CAUTION

This is an ESD (electro static discharge) sensitive device. Electrostatic charges accumulate on the human body and test equipment and can discharge without detection. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality. ESD withstand voltage of this device is up to 1500 V acc. to JESD22-A114-B.



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